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**IIP3 = 15 dBm, Gc = -0.5 dB @ 450 MHz,
MCPH6**

A5101

Features

- Wide Band: Up to Ku Band
- Low Distortion: IIP3 = 20 dBm (@ I_{CC} > 11 mA)
- SMT, Ultra Small Package : 2.0x2.1x0.85 mm
- High Conversion Gain: -0.5 dB (@ 450 MHz)
- Low Voltage Available: 1.2 V and Above
- Pb-Free, Halogen Free And ROHS Compliant

Specifications

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

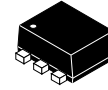
Symbol	Parameter	Ratings	Unit
V _{CBO}	Collector-to-Base Voltage	8	V
V _{CEO}	Collector-to-Emitter Voltage	6	V
V _{EBO}	Emitter-to-Base Voltage	2	V
I _{CC}	Collector Current	50	mA
P _C	Max Power Dissipation	280	mW
Topr	Operating Temperature	-40 to +85	°C
Tstg	Storage Temperature	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS (Ta = 25°C)

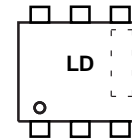
Symbol	Parameter	Ratings			Unit
		Min	Typ	Max	
V _{C1E1}	Supply Voltage	1.2	3	6	V
V _{C2E1}		1.2	3	6	V
V _{C1E2}		1.2	3	6	V
V _{C2E2}		1.2	3	6	V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

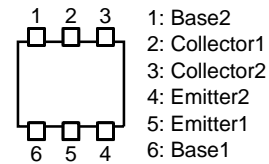


SC-88FL / MCPH6
CASE 419AS

MARKING DIAGRAM



PIN DESCRIPTION



ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

SMA5101

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

Symbol	Parameter	Conditions	Ratings			Unit
			Min	Typ	Max	
I _{C1B1O}	Collector Cutoff Current	V _{C1B1} = 5 V	–	–	1	μA
I _{C2B1O}		V _{C2B1} = 5 V	–	–	1	μA
I _{C1B2O}		V _{C1B2} = 5 V	–	–	1	μA
I _{C2B2O}		V _{C2B2} = 5 V	–	–	1	μA
I _{E1B1O}	Emitter Cutoff Current	V _{E1B1} = 1 V	–	–	1	μA
I _{E2B1O}		V _{E2B1} = 1 V	–	–	1	μA
I _{E1B2O}		V _{E1B2} = 1 V	–	–	1	μA
I _{E2B2O}		V _{E2B2} = 1 V	–	–	1	μA
h _{FE1}	DC Current Gain	V _{C1E1} = 1 V, I _{C1E1} = 3 mA	20	–	120	
h _{FE2}		V _{C2E1} = 1 V, I _{C2E1} = 3 mA	20	–	120	
h _{FE3}		V _{C1E2} = 1 V, I _{C1E2} = 3 mA	20	–	120	
h _{FE4}		V _{C2E2} = 1 V, I _{C2E2} = 3 mA	20	–	120	
Gc	Conversion Gain (Note 1)	V _{CC} = 5 V, I _{CC} = 6 mA, f(RF) = 450 MHz, f(LO) = 500 MHz, P(RF) = –15 dBm, P(LO) = –6 dBm	–	–0.5	–	dB
IIP3	Input Intercept Point (Note 1)	V _{CC} = 5 V, I _{CC} = 6 mA, f(RF1) = 450 MHz, f(RF2) = 451 MHz, f(LO) = 500 MHz, P(RF1) = P(RF2) = –15 dBm, P(LO) = –6 dBm	–	15	–	dBm

Evaluation Board



Figure 2. Evaluation Board

SMA5101

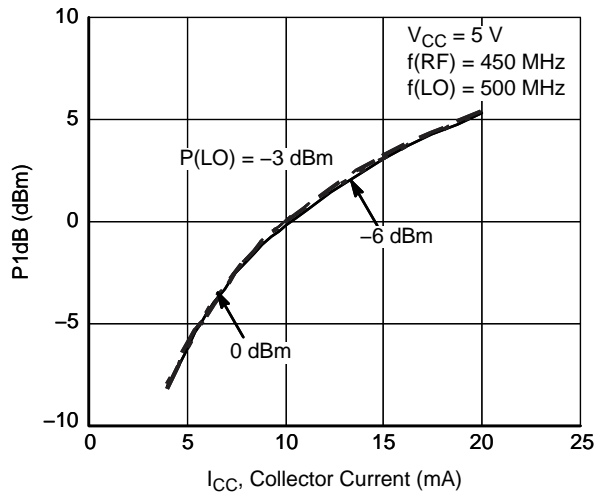


Figure 4. P1dB – I_{CC}

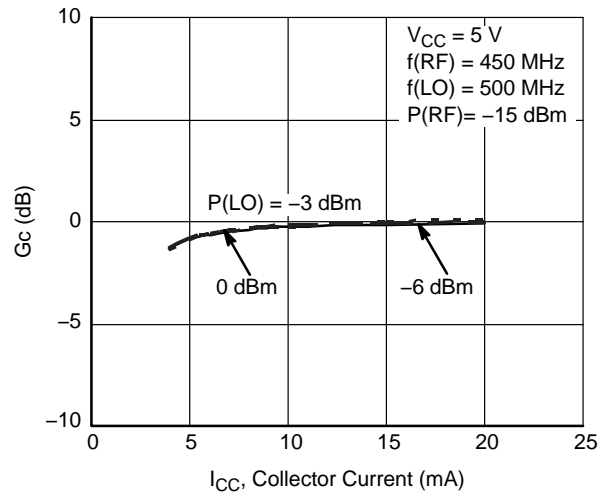


Figure 5. G_C – I_{CC}

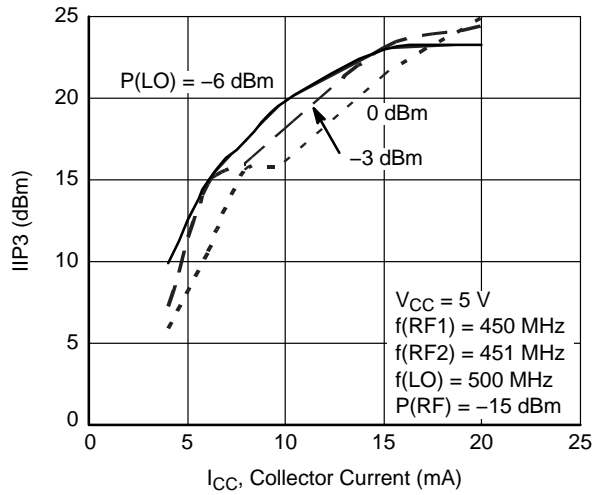
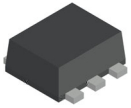


Figure 6. IIP3 – I_{CC}

ORDERING INFORMATION

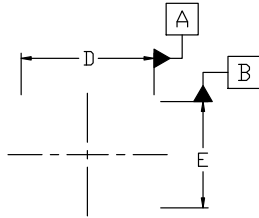
Device Order Number	Specific Device Marking	Package Type (JEITA, JEDEC)	Package Type	Shipping [†]
SMA5101-TL-H	LD	SC-88FL (Pb-Free/Halogen Free)	MCPH6 (Pb-Free/Halogen Free)	3000 / Tape & Reel

[†]For Information On Tape And Reel Specifications, Including Part Orientation And Tape Sizes, Please Refer To Our Tape And Reel Packaging Specifications Brochure, Brd8011/D.



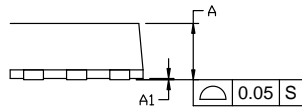
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ISSUE A

DATE 28 SEP 2022

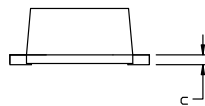


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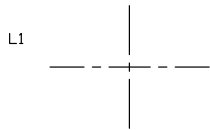
TOP VIEW



SIDE VIEW



FRONT VIEW



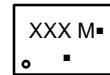
BOTTOM VIEW

NOTES:

1. NO INDUSTRY STANDARD APPLIES TO THIS PACKAGE.
2. ALL DIMENSIONS ARE IN MILLIMETERS.
3. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND THE BAR PROTRUSIONS.

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.80	0.85	0.90
A1	0.00	---	0.02
b	0.25	0.30	0.40
c	0.12	0.15	0.25
D	1.94	2.00	2.06
E	1.54	1.60	1.66
He	2.05	2.10	2.15
L	0.19	0.25	0.31
L1	0.00	0.07	0.12

GENERIC MARKING DIAGRAM*



- XXX = Specific Device Code
- M = Date Code
- = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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